

# Simulated Control of Spin Qubits in MOSFET **Quantum Dot Linear Arrays**

#### ZACH D. MERINO, BOHDAN KHROMETS, XINNING WANG, JONATHAN BAUGH

#### Introduction

We present a comprehensive simulator of electron spin qubits in electrostatically-defined quantum dots (QDs) to address challenges in designing quantum information processors.



Finite element solutions to Poisson's equation of realistic Silicon MOS are leveraged:

- Determine charge stability regions for various voltage configurations
- Engineer voltage pulses for spin qubit control
- Simulate gate operations on spin qubits in quantum circuits

#### Hubbard Hamiltonian

Hubbard parameters calculated from electrostatic potential [1]:

- Chemical potential
- Tunnel coupling
- Coulomb repulsion: onsite & interdot

$$H_{Hubbard} = H_{\mu} + H_{t} + H_{U} + H_{u}$$

$$H_{\mu} = -\sum_{\sigma=\uparrow,\downarrow} \sum_{i=1}^{N} \mu_{i} \hat{n}_{i,\sigma}$$

$$H_{t} = -\sum_{\sigma=\uparrow,\downarrow} \sum_{i

$$H_{U} = \sum_{\sigma=\uparrow,\downarrow}^{N} U_{ii} \hat{n}_{i,\uparrow} \hat{n}_{i,\downarrow}$$$$

$$H_u = \sum_{\sigma_1, \sigma_2 \in \{\uparrow, \downarrow\}} \sum_{i < j} U_{ij} \hat{n}_{i, \sigma_1} \hat{n}_{j, \sigma_2}$$

 $\left|-\frac{n}{2m}\nabla^2_{2D} + V_i(\vec{r})\right|\psi_i(\vec{r}) = \epsilon_i\psi_i(\vec{r})$ 2D Schrödinger

## IVERSITY OF WATERLOO

#### **Effective Spin Hamiltonian**

Spin Hamiltonian in rotating frame [2]:

- Stark shift: gfactor deviation
- Exchange interaction: Heitler-London/ Hund-Mulliken approximation
- $H_{Spin} = H_Z + H_I$

$$H_{Z} = \hbar \sum_{j=1}^{N} \frac{1}{2} \left[ \left( 1 + \frac{\delta g_{i}(t)}{2} \right) \omega - \omega_{RF} \right] Z_{j}$$
$$\int_{0}^{\Omega(t)} \frac{\Omega(t) \hbar}{(\cos \phi(t) X_{j} + \sin \phi(t) X_{j})}$$

$$+\frac{\Pi(t)n}{2}\left(\cos\phi(t)X_{j}+\sin\phi(t)Y_{j}\right)$$

$$\delta g_i(t) = \eta \langle \psi_i(t) | \mathcal{E}_z(t)^2 | \psi_i(t) \rangle$$
$$H_J = \sum_{i < j} \frac{J_{ij}(t)}{4} \vec{\sigma}_i \cdot \vec{\sigma}_j$$

#### Results

#### **Charge Stability Regions**

Charge stability regions for a double QD device. Coulomb repulsion and tunnel coupling features:

 Inform optimal control: pulse engineering & experiment



#### **Qubit Gate Operations**



Global Electron Spin Resonance (ESR) field with gate voltage control enables effective parameter control:

- ESR 1-qubit gates
- Voltage-only 2-qubit gates

VQE sets an upper bound on ground state energy for a molecular electronic system. Approximating the multi-electron wavefunction is crucial in capturing correlation features in a many-electron system. With proper choice of Ansatz and optimization routine, a multi-electron wavefunction can be computed efficiently and accurately [3].

A novel, custom control method maps experimental control pulses from the expected effective parameter behavior:

 Incorporation of realistic device geometries

- Account for
- electrostatic cross-
- talk between QDs
- Universal set of
- gates & quantum algorithms

#### Application

#### $CPHASE_{12}(\pi) |+\downarrow\rangle = CZ_{12} |+\downarrow\rangle = |-\downarrow\rangle$ $- \langle \sigma_{x1} \rangle$ $\langle \sigma_{y1} angle$ -----2 4 $-- \langle \sigma_{x2} \rangle$ •••• $\langle \sigma_{u2} \rangle$ $\langle \sigma_{z2} \rangle$ 6 Time $[\mu s]$ Hadamard



### **Variational Quantum Eigen-**Solver (VQE)





## **Noisy Intermediate Scale** Quantum (NISQ) Devices

Simulation of electrical noise generated by an ensemble of Random Telegraph Noise (RTN) fluctuators for varied switching times  $\tau$ . A Coupled Cluster (CC) designed VQE is applied to a 4-qubit QD linear array, which optimizes parameter  $\theta$  for a quantum circuit with gate  $R_{\chi}(\theta)$  to estimate the ground state wavefunction.



The impact on process fidelity of variational algorithm: RTN with varying electrical amplitudes and switching times  $\rightarrow$  mimic that of experimenttally observed values in real QD devices.



[1] Merino et al. AMMCS (2024): URL: https://arxiv.org/abs/2402.15499 [2] Khromets et al. AMMCS (2024), URL: https://arxiv.org/abs/2402.08146 [3] Yuxuan Du et al. npj QI (2022), DOI: 10.1038/s41534-022-00570-y.

**Acknowledgments:** This research was undertaken thanks in part to funding from NSERC and Canada First Research Excellence Fund (TQT)



